

TECHNICAL BULLETIN – B 115

Si3N4 Bonded SiC Bricks

(Silicon Carbide Bricks)

Product Description

SiC Brick (Silicon Carbide Brick) are refractory materials manufactured with SiC as the main raw material, which include 72%~99% SiC content.

Manufactured with mixing SiC granule, SiC powder and binding agent through ageing mixture, molding, drying and firing, they provide excellent thermal conductivity and great wear resistance.

Composition

SiC	≥ 72.0
Si ₃ N ₄	≥ 21.0
Fe ₂ O ₃	≤ 0.3
Si	≤ 0.3
Apparent Porosity (%)	≥ 16.0
Bulk Density (g/cm ³)	≥ 2.68



Typical Physical Data

Compressive Strength (Mpa)	Room temperature	≥ 180.0
Bending Strength (Mpa)	Room temperature	≥ 45.0
bending strength (wpa)	1400°C	≥ 55.0
Thermal Conductivity (M/m K)	650°C	18.5
Thermal Conductivity (W/m-K)	1000°C	16.0
Thermal Diffusivity (cm ² /s)	650°C	0.064
	1000°C	0.053
Linear Expansion	30°C - 1100°C	4.02 x 10 ⁻⁶ (k ⁻¹)
	30°C - 1100°C	4.06 x 10 ⁻⁶ (k ⁻¹)

Applications

- Aluminum Electrolytic Cell
- Chemical Reaction Pots
- High Temperature Furnaces
- Piping for Aluminum Transport

Note

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